SGM4684
Chip Scale Packaging, Low-Voltage 0.4Ω, Dual, SPDT Analog Switch

GENERAL DESCRIPTION

The SGM4684 is a dual, low on-resistance, low voltage, bidirectional, single-pole/double-throw (SPDT) CMOS analog switch designed to operate from a single 1.8V to 5.5V power supply. Targeted applications include battery powered equipment that benefit from low R_{ON} (0.4Ω) and fast switching speeds (t_{ON} = 25ns, t_{OFF} = 28ns).

The on resistance profile is very flat over the full analog signal range. This ensures excellent linearity and low distortion when switching audio signals.

The SGM4684 is a committed dual single-pole/double -throw (SPDT) that consist of two normally open (NO) and two normally close (NC) switches. This configuration can be used as a dual 2-to-1 multiplexer.

SGM4684 is available in Green WLCSP-2.0×1.5-10B package.

APPLICATIONS

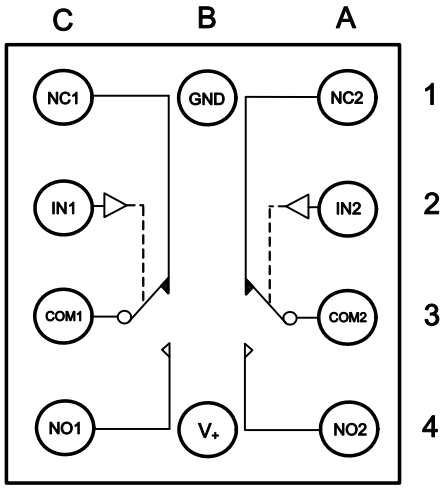
Battery-Powered, Handheld, and Portable Equipment
- Cellular/Mobile Phones
- Laptops, Notebooks, Palmtops

Communication Systems
Sample-and-Hold Circuits
Audio Signal Routing
Audio and Video Switching
Portable Test and Measurement
Medical Equipment

FEATURES

- **Low Voltage Operation: 1.8V to 5.5V**
- **Low On-Resistance: 0.4Ω (TYP)**
- **Low On-Resistance Flatness**
- **-3dB Bandwidth: 13MHz**
- **Fast Switching Times**
  - **t_{ON} 25ns**
  - **t_{OFF} 28ns**
- **Rail-to-Rail Operation**
- **Typical Power Consumption (< 0.01μW)**
- **TTL/CMOS Compatible**
- **Chip Scale Packaging**

PIN CONFIGURATION (TOP VIEW)



WLCSP-2.0×1.5-10B

FUNCTION TABLE

LOGIC	NC1, NC2	NO1, NO2
0	ON	OFF
1	OFF	ON

PACKAGE/ORDERING INFORMATION

MODEL	PIN-PACKAGE	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKAGE OPTION
SGM4684	WLCSP-2.0×1.5-10B	-40℃ to +125℃	SGM4684XG/TR	4684XG	Tape and Reel, 3000

ABSOLUTE MAXIMUM RATINGS

V_+ to GND.....-0.3V to 6V
Analog, Digital voltage range (1)..... -0.3V to (V_+) + 0.3V
Continuous Current NO, NC, or COM.....±300mA
Peak Current NO, NC, or COM ..... ±500mA
Operating Temperature Range.....-40℃ to +125℃
Junction Temperature.....150℃
Storage Temperature Range.....-65℃ to +150℃
Lead Temperature (soldering, 10s).....260℃
ESD Susceptibility
HBM.....2000V
MM.....400V

NOTES:
1. Signals on NC, NO, or COM or IN exceeding V_+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
2. Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

CAUTION

This integrated circuit can be damaged by ESD if you don’t pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SGMICRO reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time. Please contact SGMICRO sales office to get the latest datasheet.

PIN DESCRIPTION

NAME	FUNCTION
V_+	Power Supply.
GND	Ground
IN1, IN2	Digital Control Pin to Connect the COM Terminal to the NO or NC Terminals.
COM1, COM2	Common Terminal.
NO1, NO2	Normally-Open Terminal.
NC1, NC2	Normally-Closed Terminal.

NOTE: NO, NC and COM terminals may be an input or output.

ELECTRICAL CHARACTERISTICS

(V_+ = +5V ± 10%, GND = 0V, T_A = -40℃ to +125℃. Typical values are at T_A = +25℃, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		SGM4684			
				+25℃	-40℃ to +125℃	UNITS	MIN/ MAX
ANALOG SWITCH							
Analog Signal Range	V_{NO}, V_{NC}, V_{COM}				0	V	MIN
					V_+	V	MAX
On-Resistance	R_{ON}	0 ≤ V_{NO} or V_{NC} ≤ V_+, I_{COM} = -10mA, Test Circuit 1		0.4		Ω	TYP
				0.6	1.1	Ω	MAX
On-Resistance Match Between Channels	ΔR_{ON}	0 ≤ V_{NO} or V_{NC} ≤ V_+, I_{COM} = -10mA, Test Circuit 1		0.04		Ω	TYP
				0.08	0.12	Ω	MAX
On-Resistance Flatness	$R_{FLAT(ON)}$	0 ≤ V_{NO} or V_{NC} ≤ V_+, I_{COM} = -10mA, Test Circuit 1		0.1		Ω	TYP
				0.15	0.4	Ω	MAX
LEAKAGE CURRENTS							
Source OFF Leakage Current	$I_{NC(OFF)}$, $I_{NO(OFF)}$	V_{NO} or V_{NC} = 4.5V/1V, V_{COM} = 1V/4.5V, V_+ = +5.5V ,Test Circuit 2		±4		nA	TYP
				±10	±1000	nA	MAX
Channel ON Leakage Current	$I_{NC(ON)}$, $I_{NO(ON)}$, $I_{COM(ON)}$	V_{NO} or V_{NC} = V_{COM} = 1V or 4.5V, V_+ = +5.5V , Test Circuit 3		±4		nA	TYP
				±10	±1000	nA	MAX
DIGITAL INPUTS							
Input High Voltage	V_{INH}				2.4	V	MIN
Input Low Voltage	V_{INL}				0.8	V	MAX
Input Current	I_{INL} or I_{INH}	V_{IN} = V_{INH} or V_{INL}		±0.01		μA	TYP
				±0.1	±1	μA	MAX
DYNAMIC CHARACTERISTICS							
Turn-On Time	t_{ON}	V_{NO} or V_{NC} = 3V, R_L = 300Ω, C_L = 35pF, Test Circuit 4		25		ns	TYP
Turn-Off Time	t_{OFF}	V_{NO} or V_{NC} = 3V, R_L = 300Ω, C_L = 35pF, Test Circuit 4		28		ns	TYP
Charge Injection	Q	C_L = 1.0nF, V_G = 0V, R_G = 0Ω, Test Circuit 5		3		pC	TYP
Break-Before-Make Time Delay	t_D	V_{NO1} or V_{NC1} = V_{NO2} or V_{NC2} = 3V, R_L = 300Ω, C_L = 35pF, Test Circuit 6		10		ns	TYP
Off Isolation	O_{ISO}	R_L = 50Ω, C_L = 5pF, Test Circuit 7	f = 100kHz	-70		dB	TYP
			f = 10kHz	-85		dB	TYP
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, V_{COM} = 3.5V_{P-P}, R_L = 600Ω, C_L = 50pF		0.07		%	TYP
Channel-to-Channel Crosstalk	X_{TALK}	R_L = 50Ω, C_L = 5pF, Test Circuit 8	f = 100kHz	-100		dB	TYP
			f = 10kHz	-105		dB	TYP
-3dB Bandwidth	BW	R_L = 50Ω, C_L = 5pF, Test Circuit 9		13		MHz	TYP
Source OFF Capacitance	$C_{NC(OFF)}$, $C_{NO(OFF)}$			94		pF	TYP
Channel ON Capacitance	$C_{NC(ON)}$, $C_{NO(ON)}$, $C_{COM(ON)}$			450		pF	TYP
POWER REQUIREMENTS							
Power Supply Current	I_+	V_+ = +5.5V, V_{IN} = 0V or 5V		0.001		μA	TYP
					1	μA	MAX

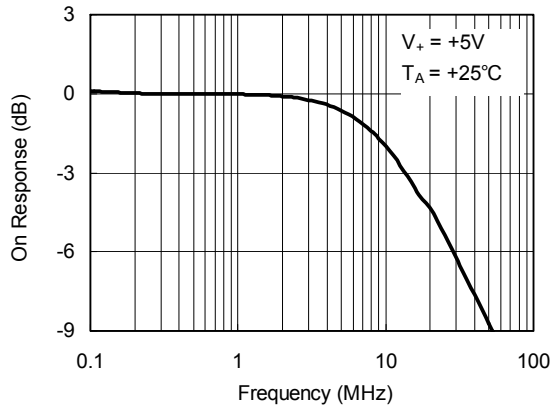
ELECTRICAL CHARACTERISTICS

(V_+ = +3V ± 10%, GND = 0V, T_A = -40℃ to +125℃. Typical values are at T_A = +25℃, unless otherwise noted.)

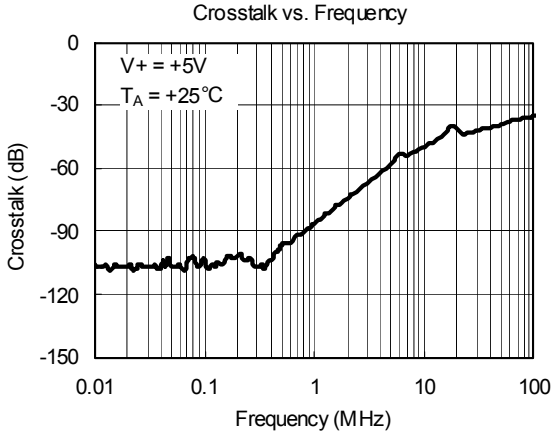
PARAMETER	SYMBOL	CONDITIONS	SGM4684			
			+25℃	-40℃ to +125℃	UNITS	MIN/ MAX
ANALOG SWITCH						
Analog Signal Range	V_{NO}, V_{NC}, V_{COM}			0	V	MIN
				V_+	V	MAX
On-Resistance	R_{ON}	0 ≤ V_{NO} or V_{NC} ≤ V_+, I_{COM} = -10mA, Test Circuit 1	0.6		Ω	TYP
			1.0	1.3	Ω	MAX
On-Resistance Match Between Channels	ΔR_{ON}	0 ≤ V_{NO} or V_{NC} ≤ V_+, I_{COM} = -10mA, Test Circuit 1	0.05		Ω	TYP
			0.1	0.13	Ω	MAX
On-Resistance Flatness	$R_{FLAT(ON)}$	0 ≤ V_{NO} or V_{NC} ≤ V_+, I_{COM} = -10mA, Test Circuit 1	0.25		Ω	TYP
			0.3	0.4	Ω	MAX
LEAKAGE CURRENTS						
Source OFF Leakage Current	$I_{NC(OFF)}$, $I_{NO(OFF)}$	V_{NO} or V_{NC} = 3V/1V, V_{COM} = 1V/3V, V_+ = +3.3V ,Test Circuit 2	±5		nA	TYP
			±11	±1000	nA	MAX
Channel ON Leakage Current	$I_{NC(ON)}$, $I_{NO(ON)}$, $I_{COM(ON)}$	V_{NO} or V_{NC} = V_{COM} = 1V or 3V, V_+ = +3.3V , Test Circuit 3	±5		nA	TYP
			±11	±1000	nA	MAX
DIGITAL INPUTS						
Input High Voltage	V_{INH}			2.0	V	MIN
Input Low Voltage	V_{INL}			0.4	V	MAX
Input Current	I_{INL} or I_{INH}	V_{IN} = V_{INH} or V_{INL}	±0.01		μA	TYP
			±0.1	±1	μA	MAX
DYNAMIC CHARACTERISTICS						
Turn-On Time	t_{ON}	V_{NO} or V_{NC} = 2V, R_L = 300Ω, C_L = 35pF, Test Circuit 4	30		ns	TYP
Turn-Off Time	t_{OFF}	V_{NO} or V_{NC} = 2V, R_L = 300Ω, C_L = 35pF, Test Circuit 4	32		ns	TYP
Charge Injection	Q	C_L = 1.0nF, V_G = 0V, R_G = 0Ω, Test Circuit 5	5		pC	TYP
Break-Before-Make Time Delay	t_D	V_{NO1} or V_{NC1} = V_{NO2} or V_{NC2} = 2V, R_L = 300Ω, C_L = 35pF, Test Circuit 6	11		ns	TYP
Off Isolation	O_{ISO}	R_L = 50Ω, C_L = 5pF, Test Circuit 7, f = 100kHz	-70		dB	TYP
		R_L = 50Ω, C_L = 5pF, Test Circuit 7, f = 10kHz	-85		dB	TYP
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, V_{COM} = $2V_{P-P}$, R_L = 600Ω, C_L = 50pF	0.065		%	TYP
Channel-to-Channel Crosstalk	X_{TALK}	R_L = 50Ω, C_L = 5pF, Test Circuit 8, f = 100kHz	-100		dB	TYP
		R_L = 50Ω, C_L = 5pF, Test Circuit 8, f = 10kHz	-105		dB	TYP
-3dB Bandwidth	BW	R_L = 50Ω, C_L = 5pF, Test Circuit 9	13		MHz	TYP
Source OFF Capacitance	$C_{NC(OFF)}$, $C_{NO(OFF)}$		94		pF	TYP
Channel ON Capacitance	$C_{NC(ON)}$, $C_{NO(ON)}$, $C_{COM(ON)}$		450		pF	TYP
POWER REQUIREMENTS						
Power Supply Current	I_+	V_+ = +3.3V, V_{IN} = 0V or 3V	0.001		μA	TYP
				1	μA	MAX

TYPICAL PERFORMANCE CHARACTERISTICS

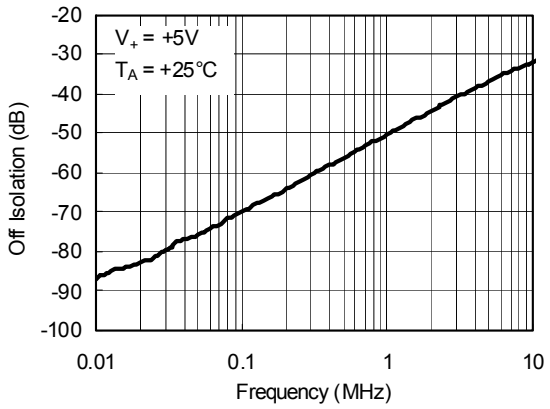
On Response vs. Frequency



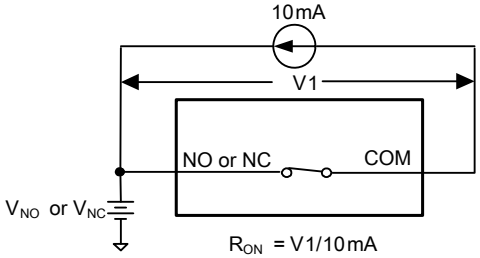
Crosstalk vs. Frequency



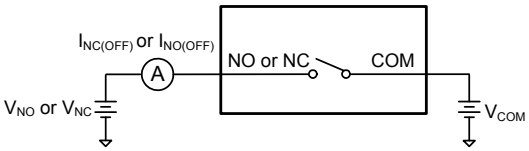
Off Isolation vs. Frequency



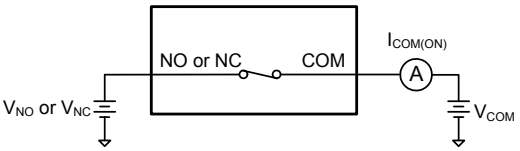
TEST CIRCUITS



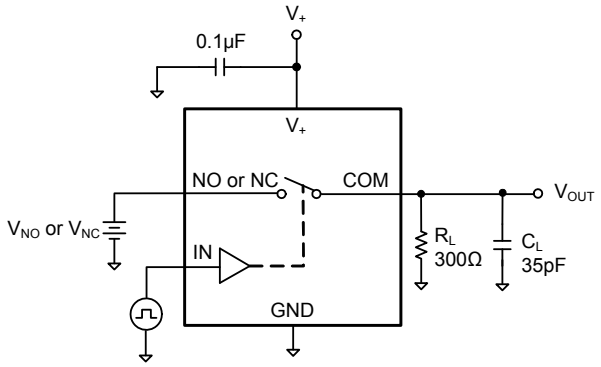
Test Circuit 1. On Resistance

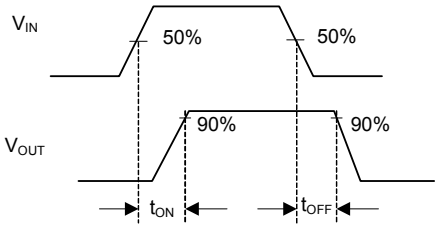


Test Circuit 2. Off Leakage

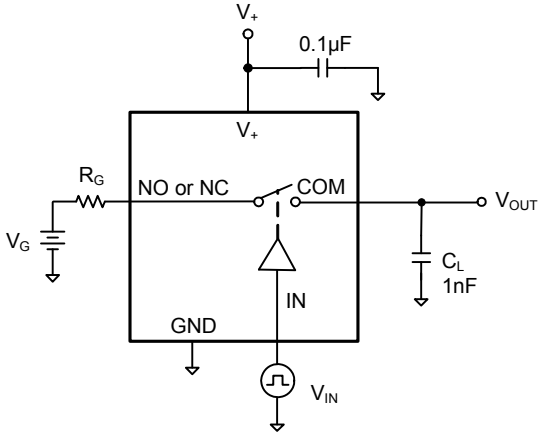


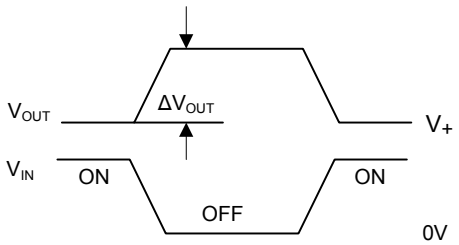
Test Circuit 3. On Leakage





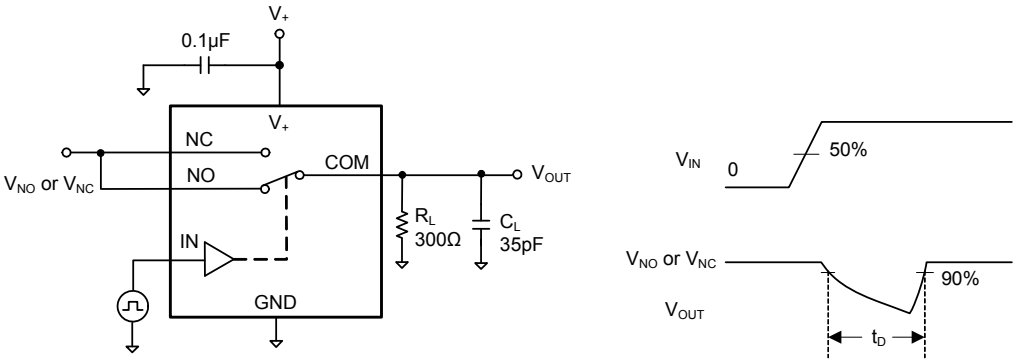
Test Circuit 4. Switching Times



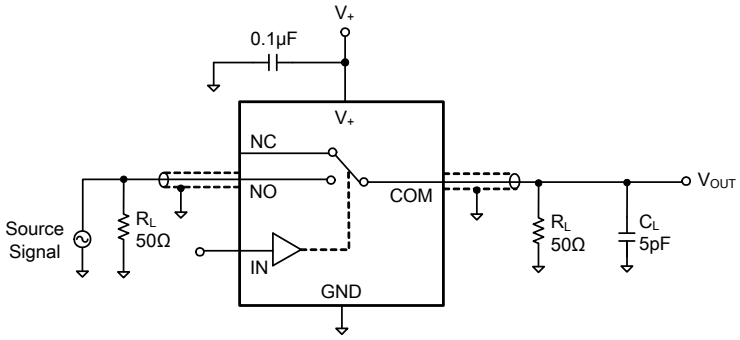


Test Circuit 5. Charge Injection

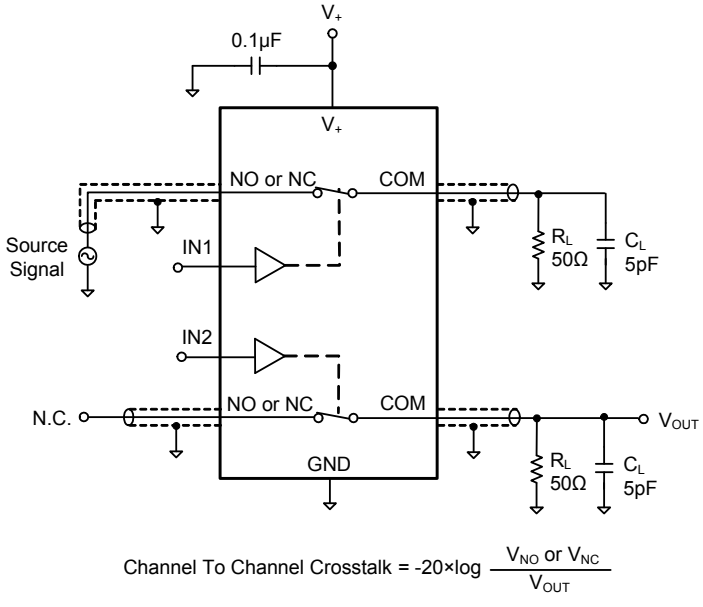
TEST CIRCUITS (Cont.)



Test Circuit 6. Break-Before-Make Time Delay, t_D



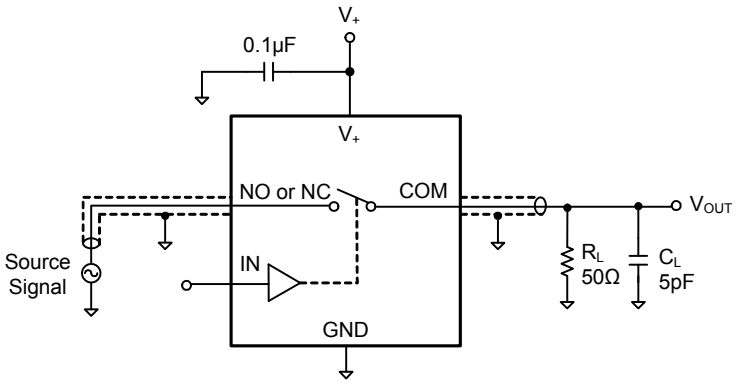
Test Circuit 7. Off Isolation



$$\text{Channel To Channel Crosstalk} = -20\times\log\frac{V_{NO}\text{ or }V_{NC}}{V_{OUT}}$$

Test Circuit 8. Channel-to-Channel Crosstalk

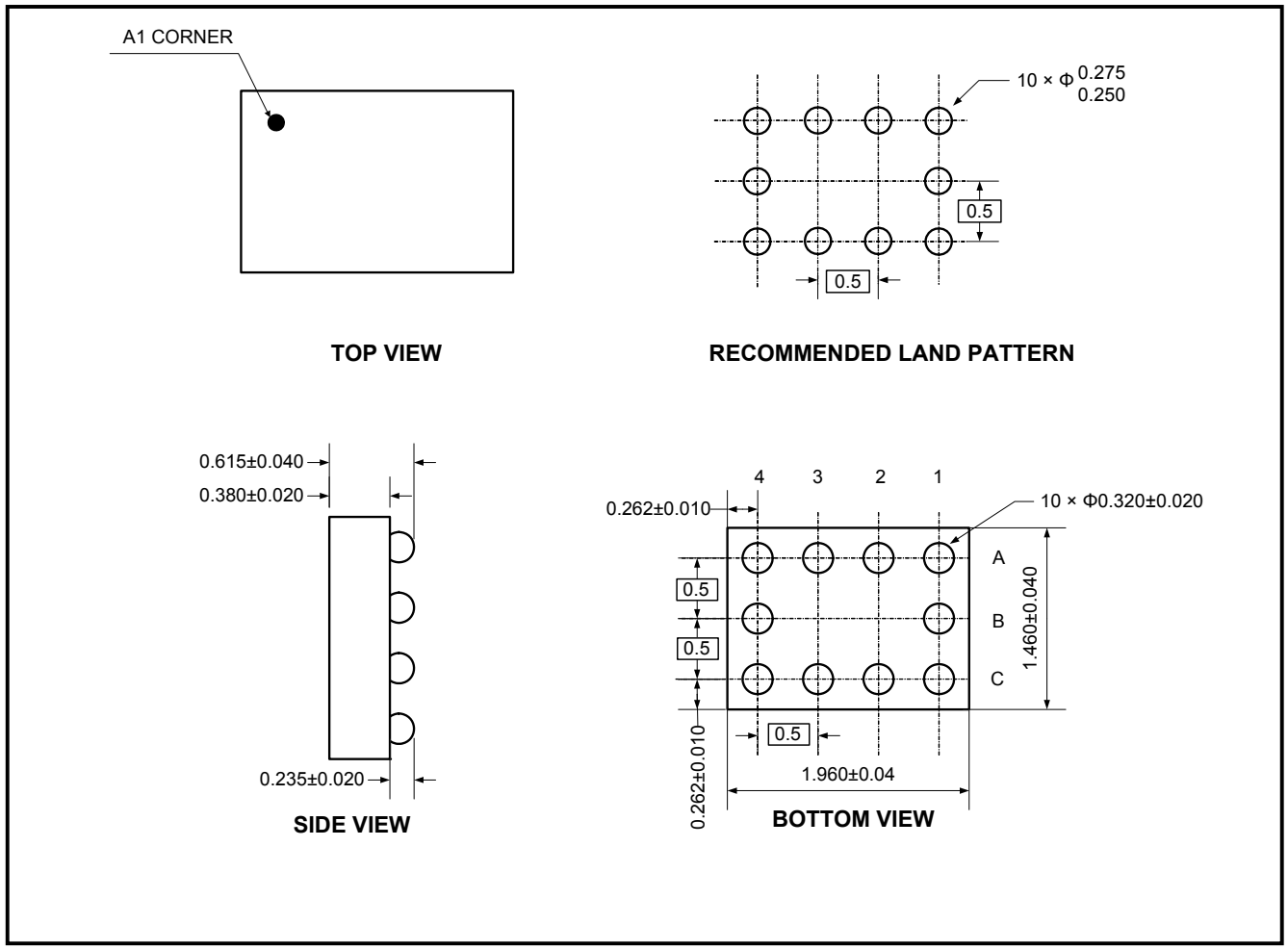
TEST CIRCUITS (Cont.)



Test Circuit 9. -3dB Bandwidth

PACKAGE OUTLINE DIMENSIONS

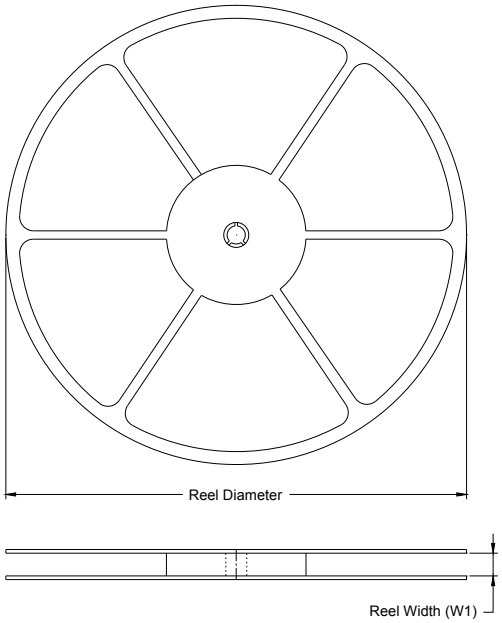
WLCSP-2.0×1.5-10B



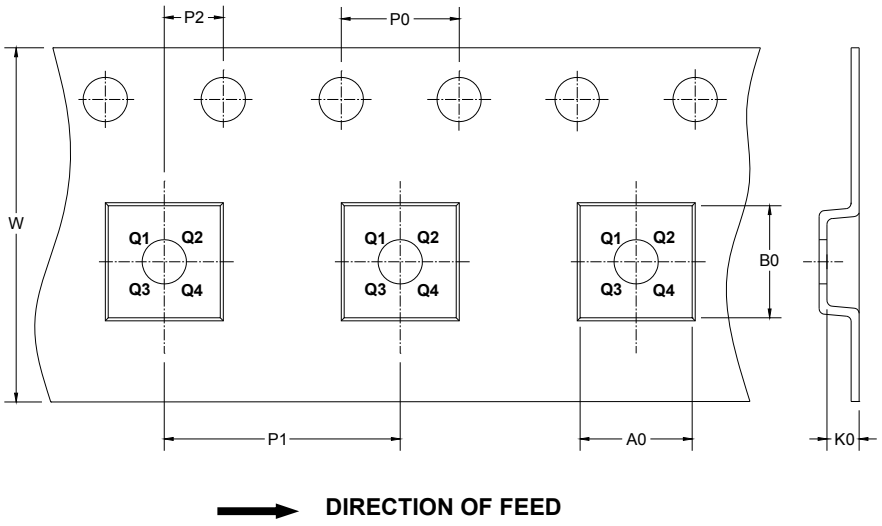
NOTE: All linear dimensions are in millimeters.

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS

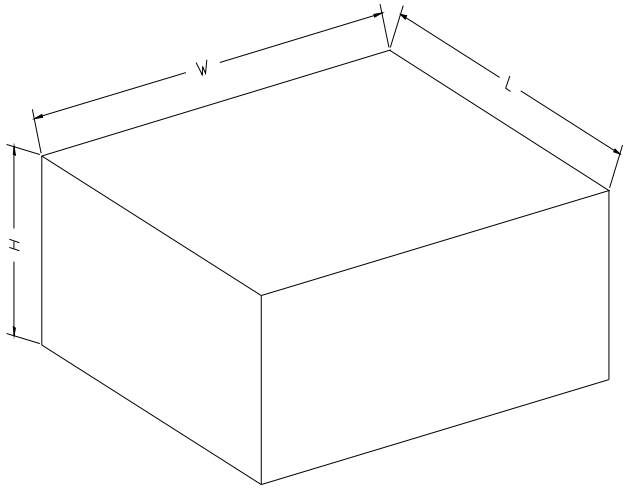


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
WLCSP-2.0×1.5-10B	7″	9.2	1.7	2.2	0.9	4.0	4.0	2.0	8.0	Q2

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7″ (Option)	368	227	224	8
7″	442	410	224	18